

**SURFACE MOUNT
FAST RECOVERY RECTIFIERS**

REVERSE VOLTAGE - **50 to 1000** Volts
FORWARD CURRENT - **3.0** Amperes

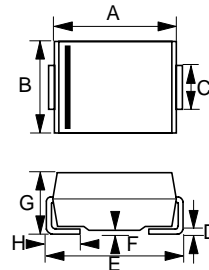
FEATURES

- Fast switching for high efficiency
- For surface mounted applications
- Glass passivated chip
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- Plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Case : Molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.003 ounces, 0.093 grams

SMB



SMB		
DIM.	MIN.	MAX.
A	4.06	4.57
B	3.30	3.94
C	1.96	2.21
D	0.15	0.31
E	5.21	5.59
F	0.05	0.20
G	2.01	2.62
H	0.76	1.52

All Dimensions in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	RS3AB	RS3BB	RS3DB	RS3GB	RS3JB	RS3KB	RS3MB	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @TL =75°C	I(AV)	3.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	IFSM	100							A
Maximum forward Voltage at 3.0A DC	VF	1.3							V
Maximum DC Reverse Current @TJ =25°C at Rated DC Blocking Voltage @TJ =125°C	IR	5.0 250							uA
Maximum Reverse Recovery Time (Note 1)	TRR	150			250		500		ns
Typical Junction Capacitance (Note 2)	CJ	50							pF
Typical Thermal Resistance (Note 3)	RθJL	10							°C/W
Typical Thermal Resistance	RθJA	50							°C/W
Operating Temperature Range	TJ	-55 to +150							°C
Storage Temperature Range	TSTG	-55 to +150							°C

NOTES : 1.Reverse Recovery Test Conditions :IF=0.5A,IR=1.0A,IRR=0.25A.
2.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
3.Thermal Resistance Junction to Lead.

